



Product data sheet

#### **Product profile** 1.

### **1.1 General description**

Ultrafast power diode in a SOT404 (D2PAK) surface-mountable plastic package.

### 1.2 Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward volt drop
- **1.3 Applications** 
  - Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations
- Surface mountable package
- Output rectifiers in high-frequency switched-mode power supplies

### 1.4 Quick reference data

#### Table 1. Quick reference data

Parameter	Conditions	Min	Тур	Max	Unit
repetitive peak reverse voltage		-	-	500	V
average forward current	square-wave pulse; δ = 0.5 ; T <sub>mb</sub> ≤ 123 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	9	A
racteristics					
forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; see <u>Figure 4</u>	-	0.9	1.03	V
characteristics					
reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/s}$ ; $T_j = 25 \text{ °C}$ ; see <u>Figure 7</u> ; see <u>Figure 6</u>	-	50	60	ns
	repetitive peak reverse voltage average forward current aracteristics forward voltage characteristics	repetitive peak reverse voltageaverage forward currentsquare-wave pulse; $\delta = 0.5$ ; $T_{mb} \leq 123$ °C; see Figure 1; see Figure 2aracteristicsforward voltageIF = 8 A; Tj = 150 °C; see Figure 4characteristicsreverse recovery timeIF = 1 A; VR = 30 V; dIF/dt = 100 A/s;	$\begin{array}{c} \mbox{repetitive peak reverse voltage} & - & \\ \mbox{average forward current} & square-wave pulse; $\delta = 0.5$; $ - $ $ $ $ $ $ $ $ $ $ $ $ $ $ $ $ $$	repetitive peak reverse voltage-average forward currentsquare-wave pulse; $\delta = 0.5$ ; $T_{mb} \leq 123$ °C; see Figure 1; see Figure 2-aracteristicsforward voltageI <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; see Figure 4-oracteristicsreverse recovery timeI <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 100 A/s;-	repetitive peak reverse voltage500average forward currentsquare-wave pulse; $\delta = 0.5$ ; $T_{mb} \leq 123$ °C; see Figure 1; see Figure 29aracteristicsforward voltage $I_F = 8 A$ ; $T_j = 150$ °C; see Figure 4-0.91.03characteristicsreverse recovery time $I_F = 1 A$ ; $V_R = 30 V$ ; $dI_F/dt = 100 A/s$ ;-5060





#### **Pinning information** 2.

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	no connection	_	
2	К	cathode <sup>[1]</sup>	mb	K — — A 001aaa020
3	А	anode		
mb	К	mounting base; cathode		
			SOT404 (D2PAK)	

[1] it is not possible to make a connection to Pin 2 of the SOT404 package

#### **Ordering information** 3.

Table 3. Ord	ering information		
Type number	Package		
	Name	Description	Version
BYV29B-500	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

#### **Limiting values** 4.

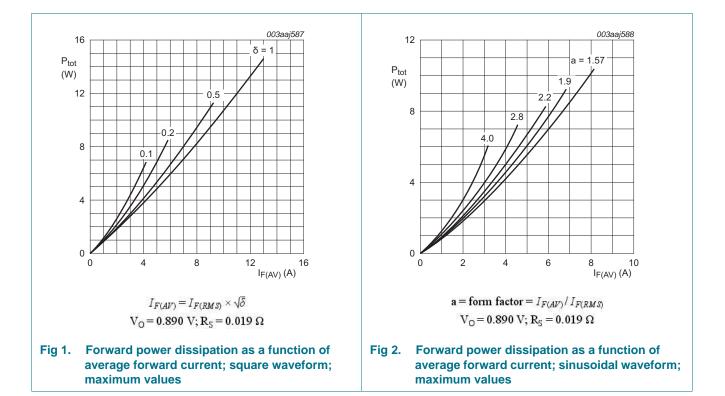
#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	500	V
V <sub>RWM</sub>	crest working reverse voltage		-	500	V
V <sub>R</sub>	reverse voltage	DC	-	500	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; δ = 0.5 ; T <sub>mb</sub> ≤ 123 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	9	А
I <sub>FRM</sub>	repetitive peak forward current	square-wave pulse; $\delta = 0.5$ ; $t_p = 25 \ \mu s$ ; $T_{mb} \le 123 \ ^\circ C$	-	18	А
I <sub>FSM</sub>	I <sub>FSM</sub> non-repetitive peak forward	$t_p$ = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C	-	100	А
current	$t_p$ = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C	-	110	А	
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

BYV29B-500

### **Ultrafast power diode**

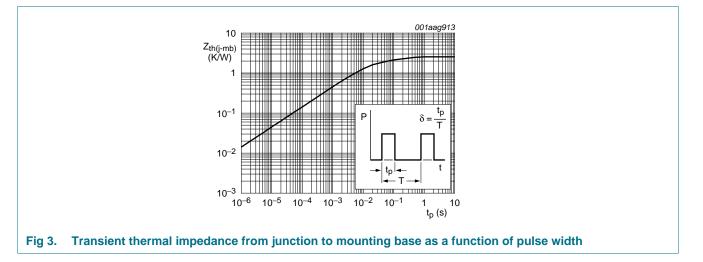


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## 5. Thermal characteristics

Table 5.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	see Figure 3		-	-	2.5	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	<u>[1]</u>	-	50	-	K/W

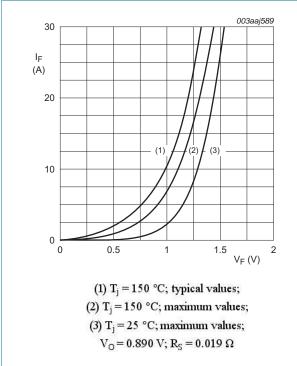
[1] Device mounted on a FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



Ultrafast power diode

## 6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; see <u>Figure 4</u>	-	0.9	1.03	V
		$I_F = 8 \text{ A}; T_j = 25 \text{ °C}; \text{ see } Figure 4$	-	1.05	1.25	V
		$I_F = 20 \text{ A}; T_j = 25 \text{ °C}; \text{ see } Figure 4$	-	1.2	1.4	V
I <sub>R</sub>	reverse current	$V_{R} = 500 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$	-	2	50	μA
		$V_R = 500 \text{ V}; \text{ T}_j = 100 \text{ °C}$	-	0.1	0.35	mA
Dynamic	characteristics					
Qr	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A/s};$ $T_j = 25 \text{ °C}; \text{ see } Figure 5; \text{ see } Figure 6$	-	40	60	nC
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/s}$ ; $T_j = 25 \text{ °C}$ ; see Figure 7; see Figure 6	-	50	60	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/s};$ $T_j = 100 \text{ °C}; \text{ see } Figure 8; \text{ see } Figure 6$	-	4	5.5	А
V <sub>FRM</sub>	forward recovery voltage	$I_F = 10 \text{ A}; \text{ d}_F/\text{d}t = 10 \text{ A/s}; T_j = 25 \text{ °C};$ see Figure 9	-	2.5	-	V



# Fig 4. Forward current as a function of forward voltage

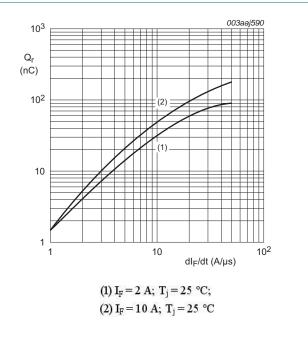


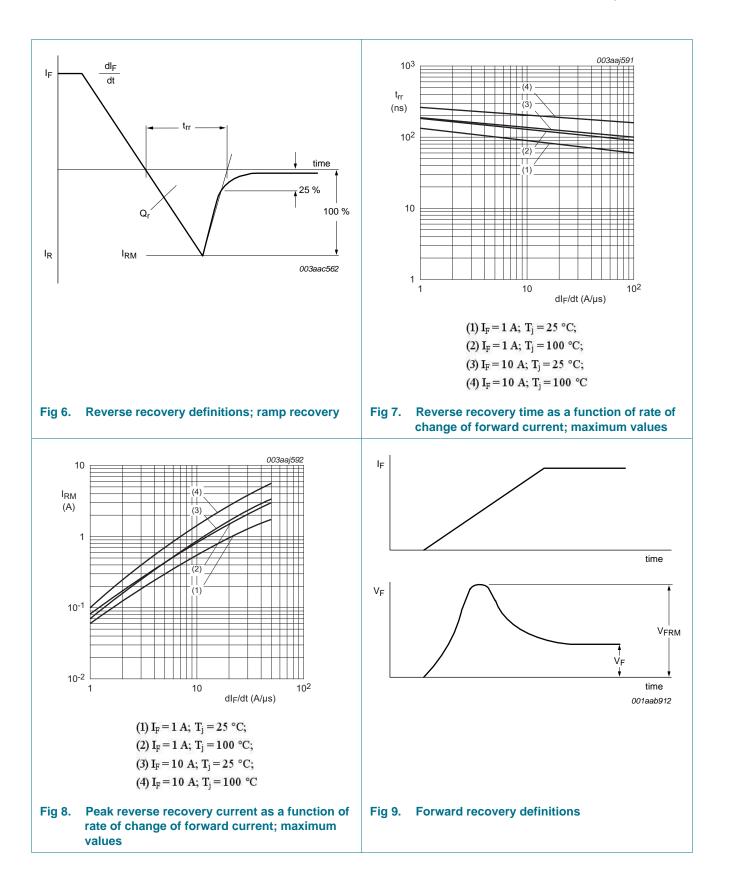
Fig 5. Recovered charge as a function of rate of change of forward current; maximum values

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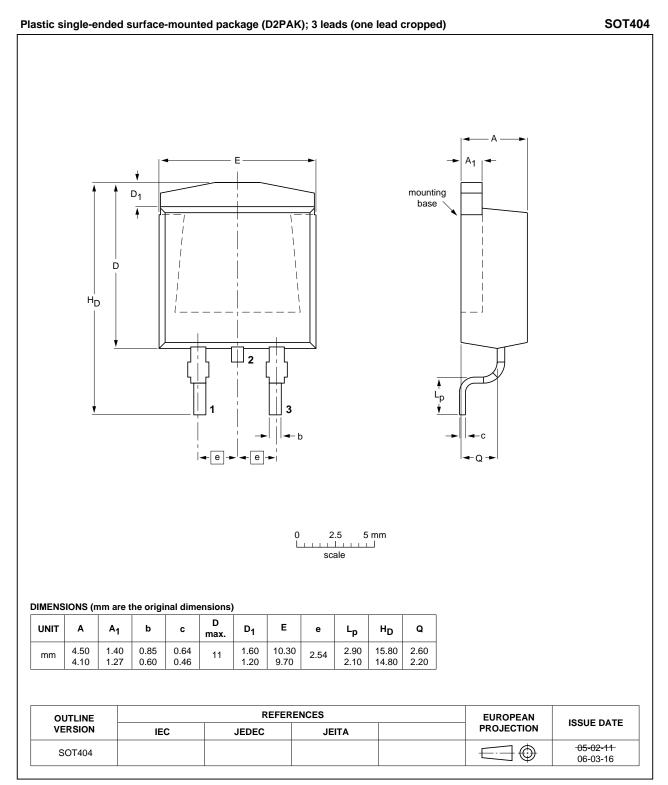
# **BYV29B-500**

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## 7. Package outline



### Fig 10. Package outline SOT404 (D2PAK)

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BYV29B-500



# 8. Revision history

Table 7. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29B-500 v.2	20120403	Product data sheet	-	BYV29B-500 v.1
Modifications:	<ul> <li>The format of NXP Semicon</li> </ul>		esigned to comply with t	he new identity guidelines of
	<ul> <li>Legal texts ha</li> </ul>	we been adapted to the new	company name where	appropriate.
BYV29B-500 v.1	20010901	Product data sheet	-	-

## 9. Legal information

### 9.1 Data sheet status

Document status[1] [2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## **11. Contents**

1	Product profile
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Limiting values2
5	Thermal characteristics4
6	Characteristics5
7	Package outline7
8	Revision history8
9	Legal information9
9.1	Data sheet status9
9.2	Definitions9
9.3	Disclaimers
9.4	Trademarks10
10	Contact information10

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